

VN10LE  
VN10LM

VN0605T  
VN0610LL

VN2222LL  
VN2222LM

### Product Summary

| Part Number | $V_{(BR)DSS}$ Min (V) | $r_{DS(on)}$ Max ( $\Omega$ ) | $V_{GS(th)}$ (V) | $I_D$ Min (A) |
|-------------|-----------------------|-------------------------------|------------------|---------------|
| VN10LE      | 60                    | 5 @ $V_{GS} = 10$ V           | 0.8 to 2.5       | 0.38          |
| VN10LM      |                       | 5 @ $V_{GS} = 10$ V           | 0.8 to 2.5       | 0.32          |
| VN0605T     |                       | 5 @ $V_{GS} = 10$ V           | 0.8 to 3.0       | 0.18          |
| VN0610LL    |                       | 5 @ $V_{GS} = 10$ V           | 0.8 to 2.5       | 0.28          |
| VN2222LL    |                       | 7.5 @ $V_{GS} = 5$ V          | 0.6 to 2.5       | 0.23          |
| VN2222LM    |                       | 7.5 @ $V_{GS} = 5$ V          | 0.6 to 2.5       | 0.26          |

### Features

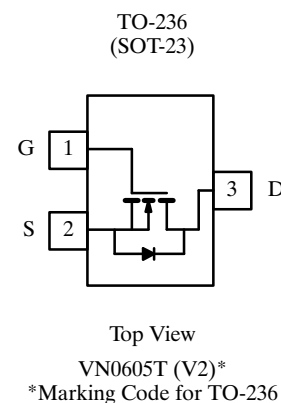
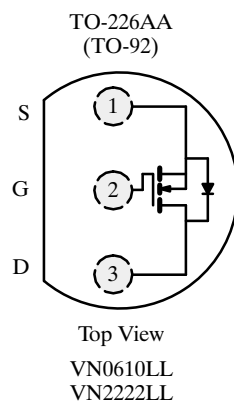
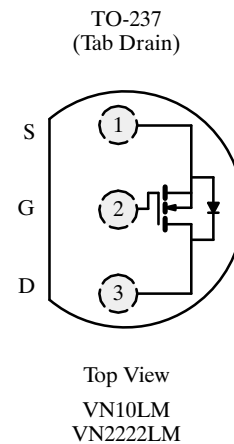
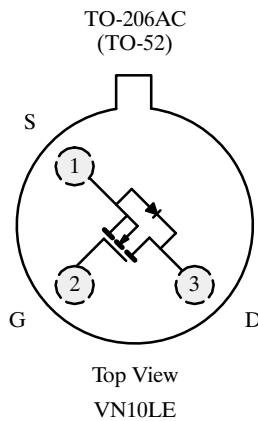
- Low On-Resistance: 2.5  $\Omega$
- Low Threshold: <2.1 V
- Low Input Capacitance: 22 pF
- Fast Switching Speed: 7 ns
- Low Input and Output Leakage

### Benefits

- Low Offset Voltage
- Low-Voltage Operation
- Easily Driven Without Buffering
- High-Speed Circuits
- Low Error Voltage

### Applications

- Direct Logic-Level Interface: TTL/CMOS
- Solid State Relays
- Drivers: Relays, Solenoids, Lamps, Hammers, Displays, Memories, Transistors, etc.
- Battery Operated Systems



# TEMIC

## Siliconix

# VN10/0605/0610/2222 Series

### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ Unless Otherwise Noted)

| Parameter                                                 | Symbol                    | VN10LE <sup>b</sup> | VN10LM   | VN0605T  | VN0610LL | VN2222LL | VN2222LM | Unit                      |
|-----------------------------------------------------------|---------------------------|---------------------|----------|----------|----------|----------|----------|---------------------------|
| Drain-Source Voltage                                      | $V_{DS}$                  | 60                  | 60       | 60       | 60       | 60       | 60       | V                         |
| Gate-Source Voltage                                       | $V_{GS}$                  | $\pm 20$            | $\pm 30$ | $\pm 30$ | $\pm 30$ | $\pm 30$ | $\pm 30$ |                           |
| Continuous Drain Current<br>( $T_J = 150^\circ\text{C}$ ) | $T_A = 25^\circ\text{C}$  | $I_D$               | 0.38     | 0.32     | 0.18     | 0.28     | 0.23     | A                         |
|                                                           | $T_A = 100^\circ\text{C}$ |                     | 0.24     | 0.2      | 0.11     | 0.17     | 0.14     |                           |
| Pulsed Drain Current <sup>a</sup>                         | $I_{DM}$                  |                     | 1.0      | 1.4      | 0.72     | 1.3      | 1.0      | 1.0                       |
| Power Dissipation                                         | $T_A = 25^\circ\text{C}$  | $P_D$               | 1.5      | 1.0      | 0.36     | 0.8      | 0.8      | W                         |
|                                                           | $T_A = 100^\circ\text{C}$ |                     | 0.6      | 0.4      | 0.14     | 0.32     | 0.32     |                           |
| Maximum Junction-to-Ambient                               | $R_{thJA}$                |                     | 400      | 125      | 350      | 156      | 156      | $^\circ\text{C}/\text{W}$ |
| Operating Junction and Storage Temperature Range          | $T_J, T_{stg}$            | $-55$ to $150$      |          |          |          |          |          | $^\circ\text{C}$          |

Notes

- a. Pulse width limited by maximum junction temperature.  
b. Reference case for all temperature testing.

### Specifications<sup>a</sup>

| Parameter                                     | Symbol               | Test Conditions                                           | Typ <sup>b</sup> | Limits                       |                   |                  |                  |                      |                  | Unit |
|-----------------------------------------------|----------------------|-----------------------------------------------------------|------------------|------------------------------|-------------------|------------------|------------------|----------------------|------------------|------|
|                                               |                      |                                                           |                  | VN10LE<br>VN10LM<br>VN0610LL |                   | VN0605T          |                  | VN2222LL<br>VN2222LM |                  |      |
|                                               |                      |                                                           |                  | Min                          | Max               | Min              | Max              | Min                  | Max              |      |
| Static                                        |                      |                                                           |                  |                              |                   |                  |                  |                      |                  |      |
| Drain-Source Breakdown Voltage                | V <sub>(BR)DSS</sub> | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 100 μA            | 70               | 60                           |                   |                  |                  | 60                   |                  | V    |
|                                               |                      | V <sub>GS</sub> = 0 V, I <sub>D</sub> = 10 μA             | 70               |                              |                   | 60               |                  |                      |                  |      |
| Gate-Threshold Voltage                        | V <sub>GS(th)</sub>  | V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 1 mA | 2.1              | 0.8                          | 2.5               | 0.8              | 3.0              | 0.6                  | 2.5              |      |
| Gate-Body Leakage                             | I <sub>GSS</sub>     | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±20 V            |                  |                              | ±100 <sub>e</sub> |                  | ±10 <sub>0</sub> |                      | ±10 <sub>0</sub> | nA   |
|                                               |                      | T <sub>J</sub> =125°C                                     |                  |                              |                   | ±50 <sub>0</sub> |                  |                      |                  |      |
|                                               |                      | V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±30 V            |                  |                              | ±100              |                  |                  |                      |                  |      |
| Zero Gate-Voltage Drain Current               | I <sub>DSS</sub>     | V <sub>DS</sub> = 50 V, V <sub>GS</sub> = 0 V             |                  |                              | 10                |                  | 1.0              |                      |                  | μA   |
|                                               |                      | T <sub>J</sub> = 125°C                                    |                  |                              | 500               |                  | 500              |                      |                  |      |
|                                               |                      | V <sub>DS</sub> = 48 V, V <sub>GS</sub> = 0 V             |                  |                              |                   |                  |                  |                      | 10               |      |
|                                               |                      | T <sub>J</sub> = 125°C                                    |                  |                              |                   |                  |                  |                      | 500              |      |
| On-State Drain Current <sup>c</sup>           | I <sub>D(on)</sub>   | V <sub>DS</sub> = 10 V, V <sub>GS</sub> = 10 V            | 1000             | 750                          |                   | 500              |                  | 750                  |                  | mA   |
| Drain-Source On-Resistance <sup>c</sup>       | r <sub>DS(on)</sub>  | V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 50 mA           | 4.5              |                              |                   |                  | 7.5              |                      |                  | Ω    |
|                                               |                      | V <sub>GS</sub> = 5 V, I <sub>D</sub> = 0.2 A             | 4.5              |                              | 7.5               |                  |                  |                      | 7.5              |      |
|                                               |                      | V <sub>GS</sub> = 10 V, I <sub>D</sub> = 0.5 A            | 2.4              |                              | 5                 |                  | 5                |                      | 7.5              |      |
|                                               |                      | T <sub>J</sub> = 125°C                                    | 4.4              |                              | 9                 |                  | 10               |                      | 13.5             |      |
| Forward Transconductance <sup>c</sup>         | g <sub>fs</sub>      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.5 A            | 230              | 100                          |                   |                  |                  | 100                  |                  | mS   |
|                                               |                      | V <sub>DS</sub> = 10 V, I <sub>D</sub> = 0.2 A            | 180              |                              |                   | 80               |                  |                      |                  |      |
| Common Source Output Conductance <sup>c</sup> | g <sub>os</sub>      | V <sub>DS</sub> = 5 V, I <sub>D</sub> = 50 mA             | 500              |                              |                   |                  |                  |                      |                  | μS   |

### Specifications<sup>a</sup>

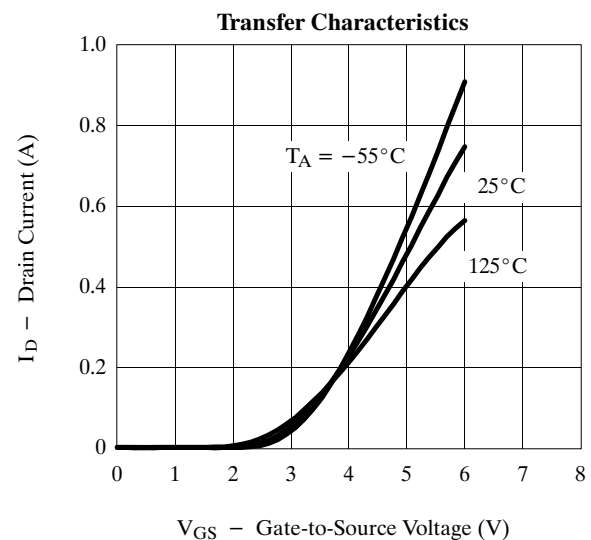
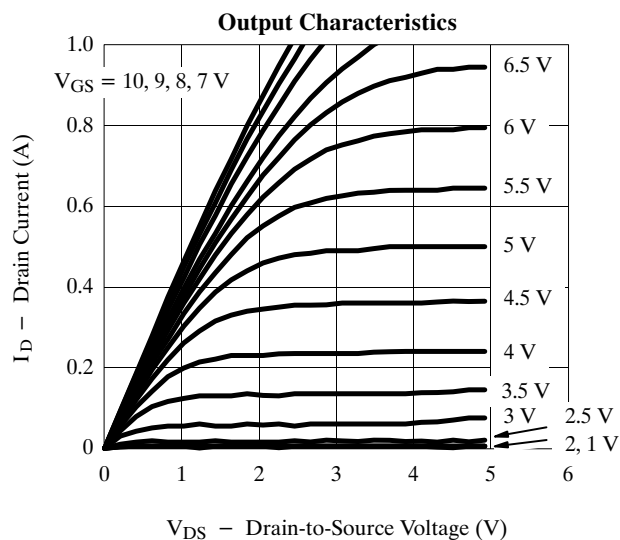
| Parameter                    | Symbol           | Test Conditions                                                                                                            | Typ <sup>b</sup> | Limits                       |     |         |     |                      |     | Unit |
|------------------------------|------------------|----------------------------------------------------------------------------------------------------------------------------|------------------|------------------------------|-----|---------|-----|----------------------|-----|------|
|                              |                  |                                                                                                                            |                  | VN10LE<br>VN10LM<br>VN0610LL |     | VN0605T |     | VN2222LL<br>VN2222LM |     |      |
|                              |                  |                                                                                                                            |                  | Min                          | Max | Min     | Max | Min                  | Max |      |
| Dynamic                      |                  |                                                                                                                            |                  |                              |     |         |     |                      |     |      |
| Input Capacitance            | C <sub>iss</sub> | V <sub>DS</sub> = 25 V, V <sub>GS</sub> = 0 V<br>f = 1 MHz                                                                 | 22               |                              | 60  |         | 60  |                      | 60  | pF   |
| Output Capacitance           | C <sub>oss</sub> |                                                                                                                            | 11               |                              | 25  |         | 25  |                      | 25  |      |
| Reverse Transfer Capacitance | C <sub>rss</sub> |                                                                                                                            | 2                |                              | 5   |         | 5   |                      | 5   |      |
| Switching <sup>d</sup>       |                  |                                                                                                                            |                  |                              |     |         |     |                      |     |      |
| Turn-On Time                 | t <sub>ON</sub>  | V <sub>DD</sub> = 15 V, R <sub>L</sub> = 23 Ω, I <sub>D</sub> ≅ 0.6 A<br>V <sub>GEN</sub> = 10 V, R <sub>G</sub> = 25 Ω    | 7                |                              | 10  |         |     |                      | 10  | ns   |
| Turn-Off Time                | t <sub>OFF</sub> |                                                                                                                            | 7                |                              | 10  |         |     |                      | 10  |      |
| Turn-On Time                 | t <sub>ON</sub>  | V <sub>DD</sub> = 30 V, R <sub>L</sub> = 150 Ω<br>I <sub>D</sub> ≅ 0.2 A<br>V <sub>GEN</sub> = 10 V, R <sub>G</sub> = 25 Ω | 7                |                              |     |         | 20  |                      |     |      |
| Turn-Off Time                | t <sub>OFF</sub> |                                                                                                                            | 11               |                              |     |         | 20  |                      |     |      |

#### Notes

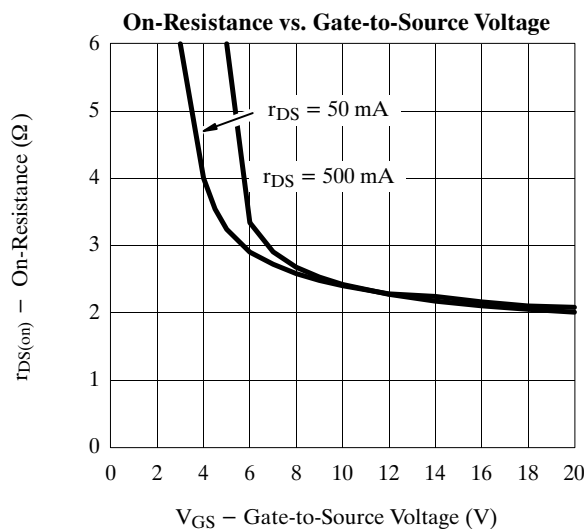
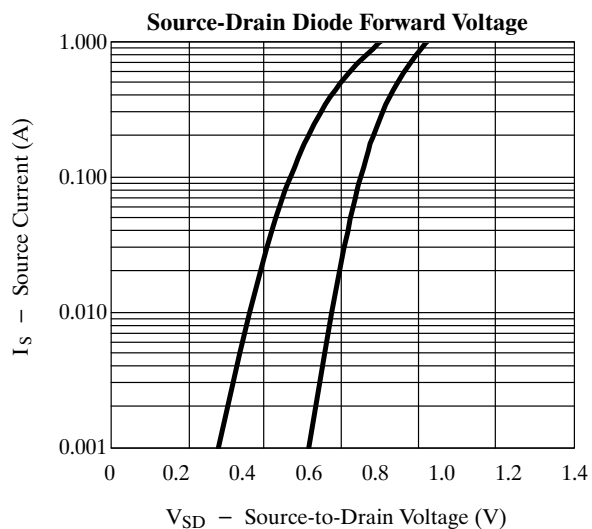
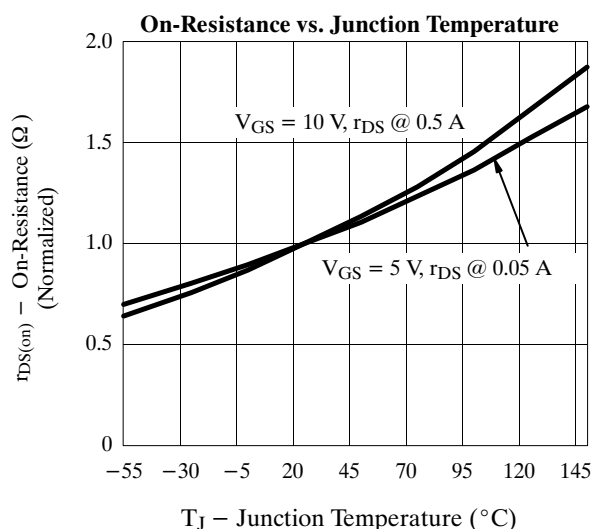
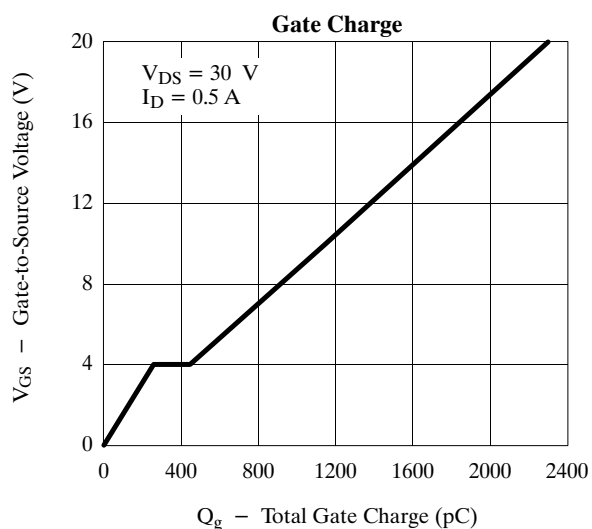
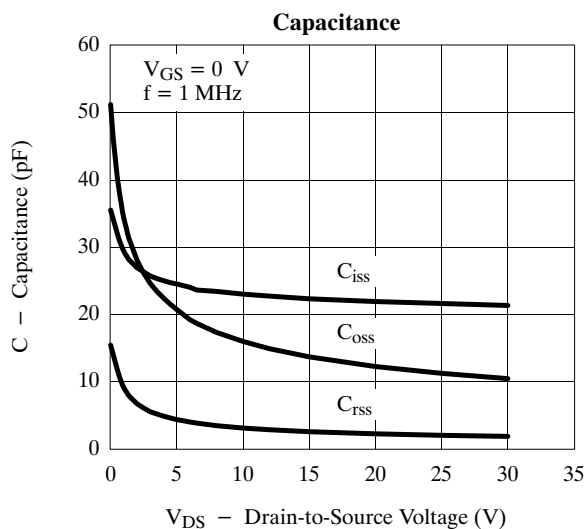
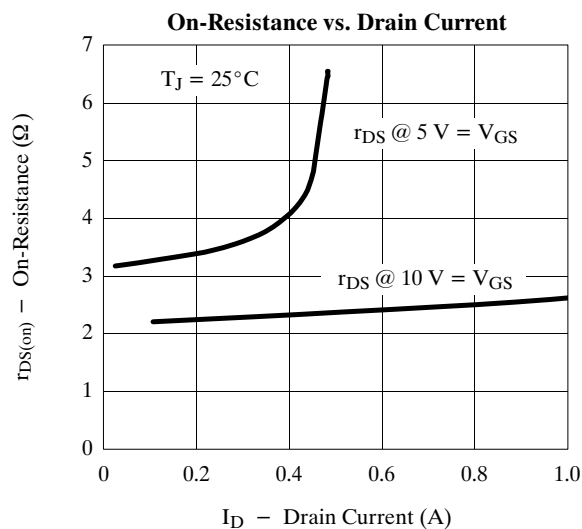
- $T_A = 25^\circ\text{C}$  unless otherwise noted.
- Typical values are for DESIGN AID ONLY, not guaranteed nor subject to production testing.
- Pulse test:  $PW \leq 300\ \mu\text{s}$  duty cycle  $\leq 3\%$ .
- Switching time is essentially independent of operating temperature.
- VN10LE only.

VNBF06

### Typical Characteristics (25°C Unless Otherwise Noted)



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### Typical Characteristics (25°C Unless Otherwise Noted)

